74AUP1G02

Low-power 2-input NOR gate

Rev. 9 — 13 January 2022

Product data sheet

1. General description

The 74AUP1G02 is a single 2-input NOR gate. Schmitt-trigger action at all inputs makes the circuit tolerant of slower input rise and fall times. This device ensures very low static and dynamic power consumption across the entire V_{CC} range from 0.8 V to 3.6 V. This device is fully specified for partial power down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the potentially damaging backflow current through the device when it is powered down.

2. Features and benefits

- Wide supply voltage range from 0.8 V to 3.6 V
- CMOS low power dissipation
- · High noise immunity
- · Overvoltage tolerant inputs to 3.6 V
- Low noise overshoot and undershoot < 10 % of V_{CC}
- I_{OFF} circuitry provides partial Power-down mode operation
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Low static power consumption; I_{CC} = 0.9 μA (maximum)
- · Complies with JEDEC standards:
 - JESD8-12 (0.8 V to 1.3 V)
 - JESD8-11 (0.9 V to 1.65 V)
 - JESD8-7 (1.2 V to 1.95 V)
 - JESD8-5 (1.8 V to 2.7 V)
 - JESD8-B (2.7 V to 3.6 V)
- ESD protection:
 - HBM JESD22-A114F Class 3A exceeds 5000 V
 - MM JESD22-A115-A exceeds 200 V
 - CDM JESD22-C101E exceeds 1000 V
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C



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3. Ordering information

Table 1. Ordering information

Type number	Package							
	Temperature range	Name	Description	Version				
74AUP1G02GW	-40 °C to +125 °C	TSSOP5	plastic thin shrink small outline package; 5 leads; body width 1.25 mm	SOT353-1				
74AUP1G02GM	-40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1.45 × 0.5 mm	SOT886				
74AUP1G02GN	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 0.9 × 1.0 × 0.35 mm	SOT1115				
74AUP1G02GS	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 1.0 × 1.0 × 0.35 mm	SOT1202				
74AUP1G02GX	-40 °C to +125 °C	X2SON5	plastic thermal enhanced extremely thin small outline package; no leads; 5 terminals; body 0.8 × 0.8 × 0.32 mm	SOT1226-3				

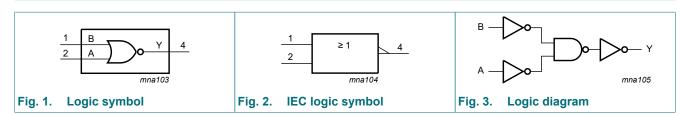
4. Marking

Table 2. Marking

14515 21 1141 14119	
Type number	Marking code[1]
74AUP1G02GW	рВ
74AUP1G02GM	рВ
74AUP1G02GN	рВ
74AUP1G02GS	рВ
74AUP1G02GX	рВ

^[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

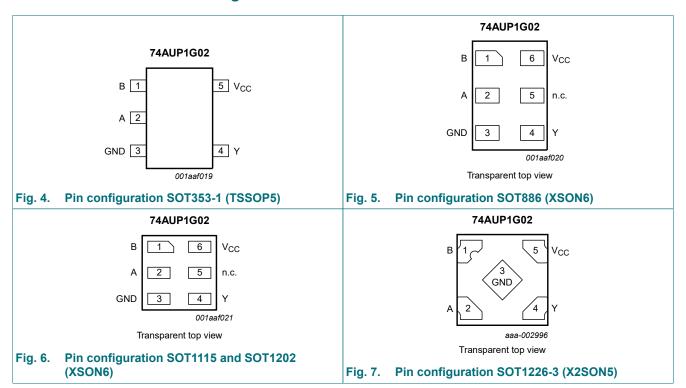
5. Functional diagram



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6. Pinning information

6.1. Pinning



6.2. Pin description

Table 3. Pin description

Symbol	Pin I		Description
	TSSOP5 and X2SON5	XSON6	
В	1	1	data input
A	2	2	data input
GND	3	3	ground (0 V)
Υ	4	4	data output
n.c.	-	5	not connected
V _{CC}	5	6	supply voltage

Product data sheet

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7. Functional description

Table 4. Function table

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level.$

Input		Output
A	В	Υ
L	L	Н
L	Н	L
Н	L	L
Н	Н	L

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+4.6	V
I _{IK}	input clamping current	V _I < 0 V	-50	-	mA
VI	input voltage	[1]	-0.5	+4.6	V
I _{OK}	output clamping current	$V_O > V_{CC}$ or $V_O < 0$ V	-	±50	mA
Vo	output voltage	Active mode and Power-down mode [1]	-0.5	+4.6	V
Io	output current	$V_O = 0 \text{ V to } V_{CC}$	-	±20	mA
I _{CC}	supply current		-	+50	mA
I _{GND}	ground current		-50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}$ [2]	-	250	mW

^[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

9. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		0.8	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	Active mode	0	V _{CC}	V
		Power-down mode; V _{CC} = 0 V	0	3.6	V
T _{amb}	ambient temperature		-40	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC} = 0.8 V to 3.6 V	0	200	ns/V

^[2] For SOT353-1 (TSSOP5) package: P_{tot} derates linearly with 3.3 mW/K above 74 °C.

For SOT886 (XSON6) package: P_{tot} derates linearly with 3.3 mW/K above 74 °C.

For SOT1115 (XSON6) package: Ptot derates linearly with 3.2 mW/K above 71 °C.

For SOT1202 (XSON6) package: P_{tot} derates linearly with 3.3 mW/K above 74 °C.

For SOT1226-3 (X2SON5) package: Ptot derates linearly with 3.0 mW/K above 67 °C.

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10. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	25 °C					
V _{IH}	HIGH-level input voltage	V _{CC} = 0.8 V	0.70 × V _{CC}	-	-	V
		V _{CC} = 0.9 V to 1.95 V	0.65 × V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 0.8 V	-	-	0.30 × V _{CC}	V
		V _{CC} = 0.9 V to 1.95 V	-	-	0.35 × V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	-	-	0.9	V
V _{OH}	HIGH-level output	$V_I = V_{IH}$ or V_{IL}				
	voltage	I_{O} = -20 μ A; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.1	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.75 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.11	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.32	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	2.05	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.9	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.72	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.6	-	-	V
V _{OL}	LOW-level output	$V_I = V_{IH}$ or V_{IL}				
	voltage	I _O = 20 μA; V _{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.3 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.31	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.31	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.31	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.44	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.31	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.44	V
I _I	input leakage current	V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V	-	-	±0.1	μΑ
I _{OFF}	power-off leakage current	V_{I} or $V_{O} = 0$ V to 3.6 V; $V_{CC} = 0$ V	-	-	±0.2	μΑ
Δl _{OFF}	additional power-off leakage current	V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V to 0.2 V	-	-	±0.2	μΑ
I _{CC}	supply current	V_I = GND or V_{CC} ; I_O = 0 A; V_{CC} = 0.8 V to 3.6 V	-	-	0.5	μΑ
ΔI _{CC}	additional supply current	$V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$ [1]	-	-	40	μΑ
Cı	input capacitance	V_{CC} = 0 V to 3.6 V; V_I = GND or V_{CC}	-	0.8	-	pF
Co	output capacitance	$V_O = GND; V_{CC} = 0 V$	-	1.7	-	pF

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = -	40 °C to +85 °C					
V _{IH}	HIGH-level input voltage	V _{CC} = 0.8 V	0.70 × V _{CC}	-	-	V
		V _{CC} = 0.9 V to 1.95 V	0.65 × V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 0.8 V	-	-	0.30 × V _{CC}	V
		V _{CC} = 0.9 V to 1.95 V	-	-	0.35 × V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	-	-	0.9	V
V _{OH}	HIGH-level output	$V_I = V_{IH}$ or V_{IL}				
	voltage	I_{O} = -20 μ A; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.1	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.7 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.03	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.30	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	1.97	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.85	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.67	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.55	-	-	V
V _{OL}	LOW-level output	$V_I = V_{IH}$ or V_{IL}				
	voltage	I _O = 20 μA; V _{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.3 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.37	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.35	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.33	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.45	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.33	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.45	V
lį	input leakage current	V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V	-	-	±0.5	μΑ
l _{OFF}	power-off leakage current	V_{I} or $V_{O} = 0$ V to 3.6 V; $V_{CC} = 0$ V	-	-	±0.5	μΑ
ΔI _{OFF}	additional power-off leakage current	V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V to 0.2 V	-	-	±0.6	μΑ
I _{CC}	supply current	V_{I} = GND or V_{CC} ; I_{O} = 0 A; V_{CC} = 0.8 V to 3.6 V	-	-	0.9	μΑ
ΔI _{CC}	additional supply current	$V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$ [1]	-	-	50	μΑ
T _{amb} = -	40 °C to +125 °C					
V _{IH}	HIGH-level input voltage	V _{CC} = 0.8 V	0.75 × V _{CC}	-	-	V
		V _{CC} = 0.9 V to 1.95 V	0.70 × V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 0.8 V	-	-	0.25 × V _{CC}	V
		V _{CC} = 0.9 V to 1.95 V	-	-	0.30 × V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	_	_	0.9	V

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{OH}	HIGH-level output	$V_I = V_{IH}$ or V_{IL}				
	voltage	I_{O} = -20 μ A; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.11	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.6 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	0.93	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.17	-	-	V
		I_{O} = -2.3 mA; V_{CC} = 2.3 V	1.77	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.67	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.40	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.30	-	-	V
V _{OL}	LOW-level output	$V_I = V_{IH}$ or V_{IL}				
	voltage	I _O = 20 μA; V _{CC} = 0.8 V to 3.6 V	-	-	0.11	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.33 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.41	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.39	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.36	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.50	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.36	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.50	V
I	input leakage current	V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V	-	-	±0.75	μΑ
I _{OFF}	power-off leakage current	V_{I} or $V_{O} = 0$ V to 3.6 V; $V_{CC} = 0$ V	-	-	±0.75	μΑ
Δl _{OFF}	additional power-off leakage current	V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V to 0.2 V	-	-	±0.75	μΑ
I _{CC}	supply current	V_{I} = GND or V_{CC} ; I_{O} = 0 A; V_{CC} = 0.8 V to 3.6 V	-	-	1.4	μΑ
ΔI_{CC}	additional supply current	$V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}; V_{CC} = 3.3 \text{ V} $ [1]	-	-	75	μA

^[1] One input at V_{CC} - 0.6 V, other input at V_{CC} or GND.

11. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 9.

Symbol	Parameter	Conditions	Min	Typ [1]	Max	Unit		
T _{amb} = 2	T _{amb} = 25 °C; C _L = 5 pF							
t _{pd}	propagation delay	A, B to Y; see <u>Fig. 8</u> [2]						
		V _{CC} = 0.8 V	-	17.0	-	ns		
		V _{CC} = 1.1 V to 1.3 V	2.5	5.1	10.8	ns		
		V _{CC} = 1.4 V to 1.6 V	1.6	3.7	6.7	ns		
		V _{CC} = 1.65 V to 1.95 V	1.3	3.0	5.3	ns		
		V _{CC} = 2.3 V to 2.7 V	1.0	2.4	3.9	ns		
		V _{CC} = 3.0 V to 3.6 V	1.0	2.2	3.4	ns		

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Symbol	Parameter	Conditions		Min	Typ [1]	Max	Unit
T _{amb} = 2	25 °C; C _L = 10 pF						
t _{pd}	propagation delay	A, B to Y; see Fig. 8	[2]				
		V _{CC} = 0.8 V		-	20.4	-	ns
		V _{CC} = 1.1 V to 1.3 V		2.4	6.0	12.8	ns
		V _{CC} = 1.4 V to 1.6 V		1.9	4.3	7.9	ns
		V _{CC} = 1.65 V to 1.95 V		1.6	3.6	6.2	ns
		V _{CC} = 2.3 V to 2.7 V		1.4	3.0	4.7	ns
		V _{CC} = 3.0 V to 3.6 V		1.3	2.7	4.2	ns
T _{amb} = 2	25 °C; C _L = 15 pF		<u>'</u>				
t _{pd}	propagation delay	A, B to Y; see Fig. 8	[2]				
		V _{CC} = 0.8 V		-	23.9	-	ns
		V _{CC} = 1.1 V to 1.3 V		3.4	6.8	14.6	ns
		V _{CC} = 1.4 V to 1.6 V		2.3	4.8	8.9	ns
		V _{CC} = 1.65 V to 1.95 V		1.9	4.0	7.0	ns
		V _{CC} = 2.3 V to 2.7 V		1.7	3.4	5.4	ns
		V _{CC} = 3.0 V to 3.6 V		1.6	3.2	4.8	ns
T _{amb} = 2	25 °C; C _L = 30 pF		'				
t _{pd}	propagation delay	A, B to Y; see Fig. 8	[2]				
		V _{CC} = 0.8 V		-	34.2	-	ns
		V _{CC} = 1.1 V to 1.3 V		4.6	9.0	19.9	ns
		V _{CC} = 1.4 V to 1.6 V		3.4	6.4	11.8	ns
		V _{CC} = 1.65 V to 1.95 V		2.6	5.3	9.3	ns
		V _{CC} = 2.3 V to 2.7 V		2.4	4.5	7.1	ns
		V _{CC} = 3.0 V to 3.6 V		2.3	4.2	6.4	ns
T _{amb} = 2	25 °C		'				
C _{PD}	power dissipation	$f = 1 \text{ MHz}; V_I = \text{GND to } V_{CC}$	[3]				
	capacitance	V _{CC} = 0.8 V		-	2.6	-	pF
		V _{CC} = 1.1 V to 1.3 V		-	2.7	-	pF
		V _{CC} = 1.4 V to 1.6 V		-	2.9	-	pF
		V _{CC} = 1.65 V to 1.95 V		-	3.1	-	pF
		V _{CC} = 2.3 V to 2.7 V		-	3.5	-	pF
		V _{CC} = 3.0 V to 3.6 V		-	4.1	-	pF
	1				1		

^[1] All typical values are measured at nominal V_{CC} .

f_i = input frequency in MHz;

 f_o = output frequency in MHz;

 C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

 ^[2] t_{pd} is the same as t_{PLH} and t_{PHL}.
 [3] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).
 P_D = C_{PD} × V_{CC}² × f_i × N + Σ(C_L × V_{CC}² × f_o) where:

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Table 9. Dynamic characteristics

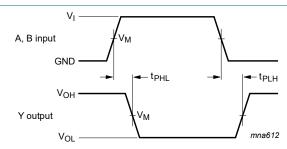
Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 9

Symbol	Parameter	Conditions		-40 °C t	o +85 °C	-40 °C to +125 °C		Unit
			Min	Max	Min	Max		
C _L = 5 p	F							
t _{pd}	propagation delay	A, B to Y; see Fig. 8	[1]					
		V _{CC} = 1.1 V to 1.3 V		2.1	12.1	2.1	13.4	ns
		V _{CC} = 1.4 V to 1.6 V		1.4	7.8	1.4	8.6	ns
		V _{CC} = 1.65 V to 1.95 V		1.1	6.2	1.1	6.9	ns
		V _{CC} = 2.3 V to 2.7 V		0.9	4.6	0.9	5.1	ns
		V _{CC} = 3.0 V to 3.6 V		8.0	4.0	0.8	4.4	ns
C _L = 10	pF		·					
t _{pd}	propagation delay	A, B to Y; see Fig. 8	[1]					
		V _{CC} = 1.1 V to 1.3 V		2.2	14.3	2.2	15.8	ns
		V _{CC} = 1.4 V to 1.6 V		1.7	9.2	1.7	10.2	ns
		V _{CC} = 1.65 V to 1.95 V		1.5	7.3	1.5	8.1	ns
		V _{CC} = 2.3 V to 2.7 V		1.2	5.6	1.2	6.2	ns
		V _{CC} = 3.0 V to 3.6 V		1.2	5.0	1.2	5.5	ns
C _L = 15	pF							
t _{pd}	propagation delay	A, B to Y; see Fig. 8	[1]					
		V _{CC} = 1.1 V to 1.3 V		3.1	16.4	3.1	18.1	ns
		V _{CC} = 1.4 V to 1.6 V		2.0	10.4	2.0	11.5	ns
		V _{CC} = 1.65 V to 1.95 V		1.7	8.3	1.7	9.2	ns
		V _{CC} = 2.3 V to 2.7 V		1.5	6.3	1.5	7.0	ns
		V _{CC} = 3.0 V to 3.6 V		1.4	5.7	1.4	6.3	ns
C _L = 30	pF		·					
t _{pd}	propagation delay	A, B to Y; see Fig. 8	[1]					
		V _{CC} = 1.1 V to 1.3 V		4.1	22.4	4.1	24.7	ns
		V _{CC} = 1.4 V to 1.6 V		2.9	13.9	2.9	15.3	ns
		V _{CC} = 1.65 V to 1.95 V		2.3	11.1	2.3	12.3	ns
		V _{CC} = 2.3 V to 2.7 V		2.1	8.5	2.1	9.4	ns
		V _{CC} = 3.0 V to 3.6 V		2.1	7.7	2.1	8.5	ns

^[1] t_{pd} is the same as t_{PLH} and t_{PHL} .

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11.1. Waveform and test circuit



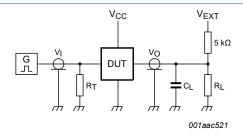
Measurement points are given in Table 10.

Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig. 8. The data input (A or B) to output (Y) propagation delays

Table 10. Measurement points

Supply voltage	Output	Input		
V _{CC}	V _M	V _M	V _I	$t_r = t_f$
0.8 V to 3.6 V	0.5 × V _{CC}	0.5 × V _{CC}	V _{CC}	≤ 3.0 ns



Test data is given in Table 11.

Definitions for test circuit:

R_L = Load resistance.

 C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to the output impedance Z_o of the pulse generator.

 V_{EXT} = External voltage for measuring switching times.

Fig. 9. Test circuit for measuring switching times

Table 11. Test data

Supply voltage	Load		V _{EXT}		
V _{CC}	CL	R _L [1]	t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 kΩ or 1 MΩ	open	GND	2 × V _{CC}

[1] For measuring enable and disable times R_L = 5 $k\Omega.$

For measuring propagation delays, setup and hold times and pulse width R_{L} = 1 $\mbox{M}\Omega.$

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12. Package outline

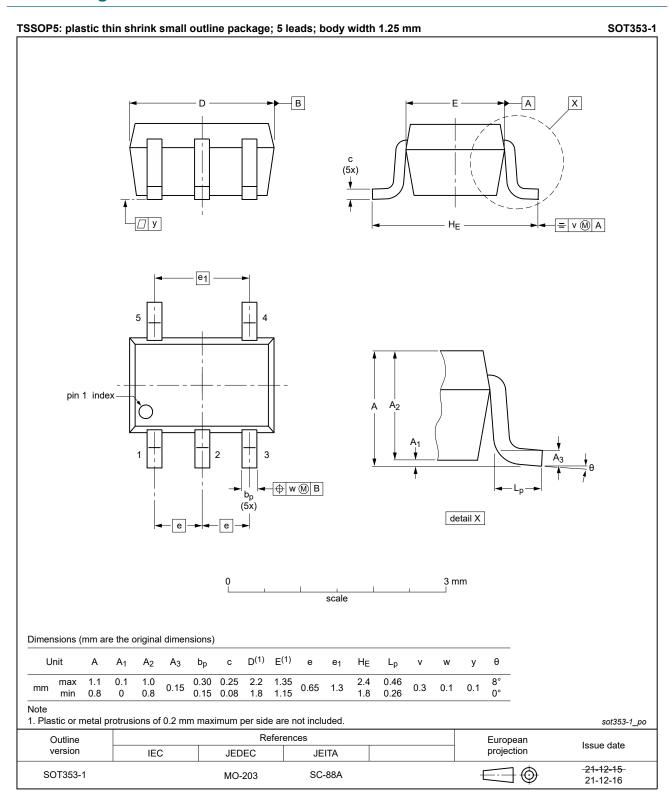


Fig. 10. Package outline SOT353-1 (TSSOP5)

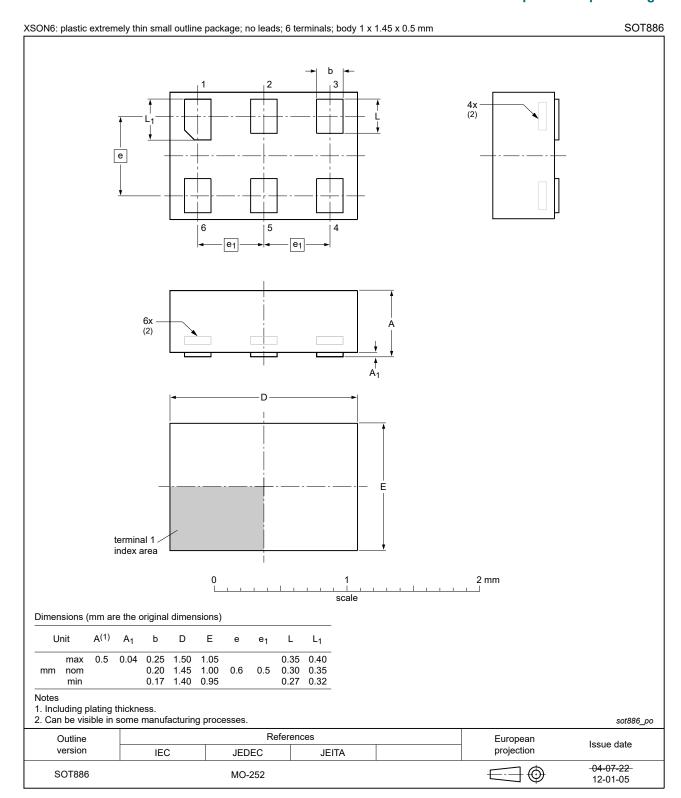


Fig. 11. Package outline SOT886 (XSON6)

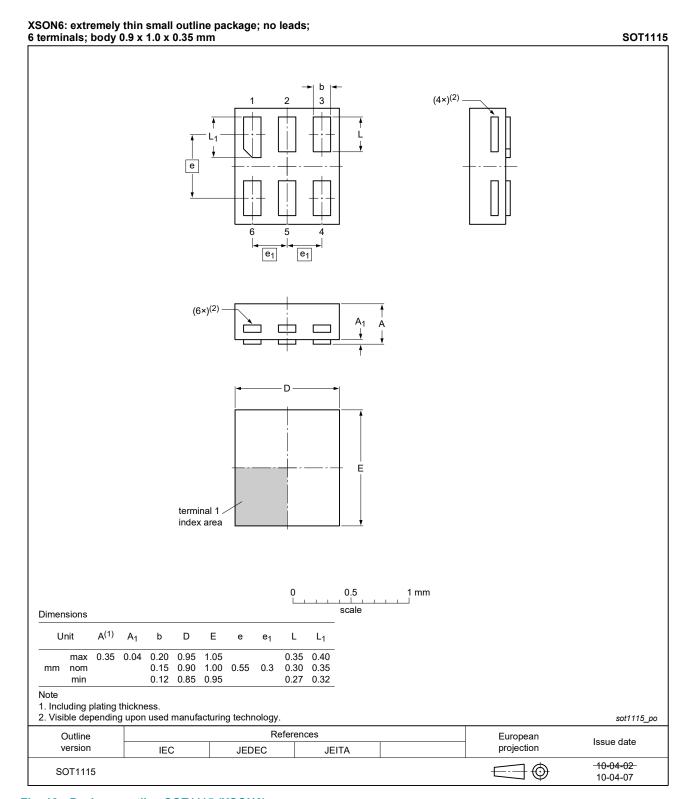


Fig. 12. Package outline SOT1115 (XSON6)

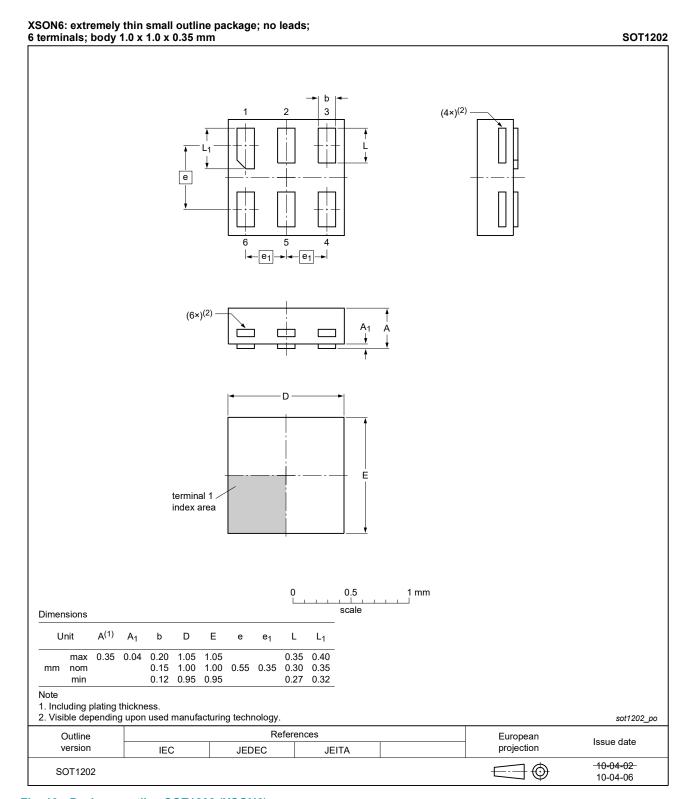


Fig. 13. Package outline SOT1202 (XSON6)

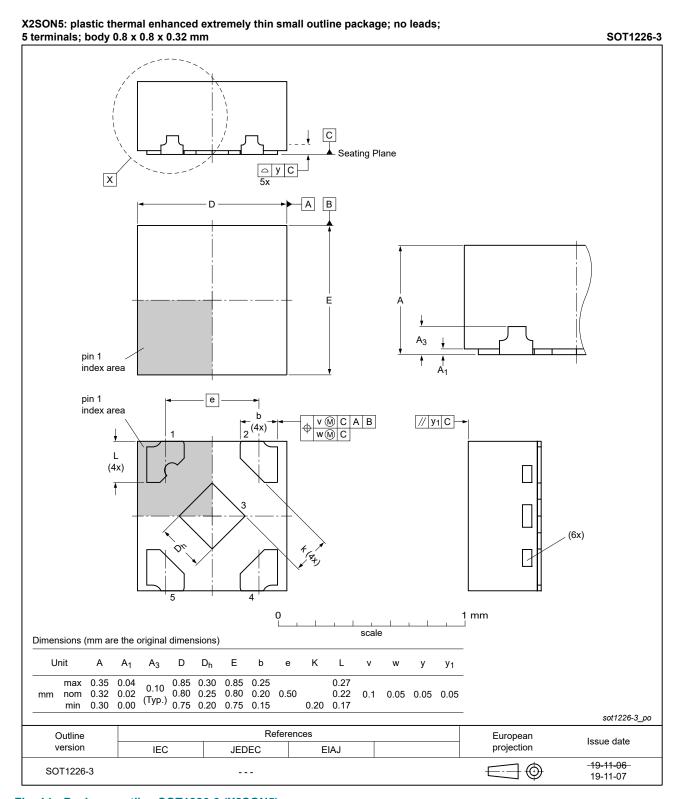


Fig. 14. Package outline SOT1226-3 (X2SON5)

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13. Abbreviations

Table 12. Abbreviations

Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model

14. Revision history

Table 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
74AUP1G02 v.9	20220113	Product data sheet	-	74AUP1G02 v.8		
Modifications:	• <u>Fig. 10</u> : Pad	Fig. 10: Package outline drawing for SOT353-1 (TSSOP5) has changed.				
74AUP1G02 v.8	20210803	Product data sheet	-	74AUP1G02 v.7		
Modifications:	guidelines of Legal texts Legal texts Type number SOT1226 (X Section 1 are IEC logic sy	guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. Type number 74AUP1G02GF (SOT891/XSON6) removed.				
74AUP1G02 v.7	20150121	Product data sheet	-	74AUP1G02 v.6		
Modifications:	• X2SON5 ac	X2SON5 added to pin description table (<u>Table 3</u>).				
74AUP1G02 v.6	20120627	Product data sheet	-	74AUP1G02 v.5		
Modifications:	Added type	Added type number 74AUP1G02GX (SOT1226).				
74AUP1G02 v.5	20120216	Product data sheet	-	74AUP1G02 v.4		
Modifications:		 Logic diagram (Fig. 3) modified. Package outline drawing of SOT886 (Fig. 11) modified. 				
74AUP1G02 v.4	20111115	Product data sheet	-	74AUP1G02 v.3		
Modifications:	Legal pages	Legal pages updated.				
74AUP1G02 v.3	20101012	Product data sheet	-	74AUP1G02 v.2		
74AUP1G02 v.2	20060628	Product data sheet	-	74AUP1G02 v.1		
74AUP1G02 v.1	20050718	Product data sheet	-	-		

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15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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